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Diodes Incorporated BFS17NTA

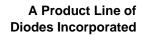
For any questions, you can email us directly: <a href="mailto:sales@integrated-circuit.com">sales@integrated-circuit.com</a>



Datasheet of BFS17NTA - TRANS RF NPN 3.2GHZ 11V SOT23

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BFS17N

#### **NPN RF TRANSISTOR IN SOT23**

#### **Features**

- 3.2GHz unity gain for RF switching applications
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP capable (Note 4)

### **Applications**

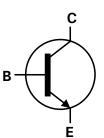
#### **Mechanical Data**

- Case: SOT23
- Case material: molded plastic. "Green" molding compound.
- UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.008 grams (approximate)

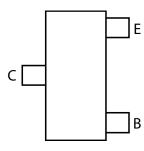
# RF switch







Device symbol



Top View Pin Out

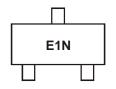
#### Ordering Information (Notes 4 & 5)

Product	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
BFS17NTA	AEC-Q101	E1N	7	8	3,000
BFS17NQTA	Automotive	E1N	7	8	3,000

#### Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen and Antimony free, "Green" and Lead-Free.
- 3. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified.
- 5. For packaging details, go to our website at http://www.diodes.com.

### **Marking Information**



E1N = Product type Marking Code



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#### **Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	20	V
Collector-Emitter Voltage	$V_{CEO}$	11	V
Emitter-Base Voltage	V <sub>EBO</sub>	3	V
Continuous Collector Current	Ic	50	mA

#### Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
Power Dissipation	(Note 6)	D-	310	mW	
Fower Dissipation	(Note 7)	P <sub>D</sub>	350		
Thermal Desistance, Junction to Ambient	(Note 6)	<b>D</b>	403	°C/W	
Thermal Resistance, Junction to Ambient	(Note 7)	$R_{\theta JA}$	357	*C/VV	
Thermal Resistance, Junction to Leads (Note 8)		R <sub>0JL</sub>	350	°C/W	
Operating and Storage Temperature Range		$T_{J,}T_{STG}$	-55 to +150	°C	

#### ESD Ratings (Note 9)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	2,000	V	2
Electrostatic Discharge - Machine Model	ESD MM	100	V	Α

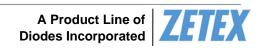
Notes:

- 6. For the device mounted on minimum recommended pad layout FR4 PCB with high coverage of single sided 1oz copper in still air condition;
- 7. Same as Note 6, expect the device is mounted on 15mm X 15mm X 1.6mm FR4 PCB
- 8. Thermal resistance from junction to solder-point (at the end of the leads). 9. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

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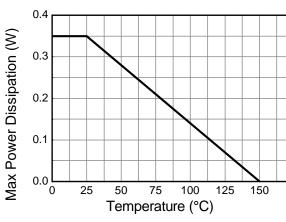
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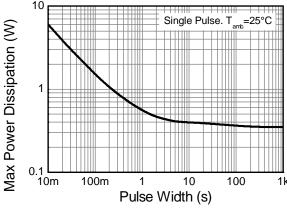
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### **Thermal Characteristics and Derating information**



**Derating Curve** 

**Transient Thermal Impedance** 



**Pulse Power Dissipation** 



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## **Electrical Characteristics** (@ $T_A = +25$ °C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	20	_	_	V	$I_C = 10\mu A$
Collector-Emitter Breakdown Voltage (Note 10)	BV <sub>CEO</sub>	11	_	_	V	I <sub>C</sub> = 1mA
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	3	_	_	V	I <sub>E</sub> = 10μA
Collector Cutoff Current	I <sub>CBO</sub>	_	_	0.5	μA	V <sub>CB</sub> = 10V
Emitter Cutoff Current	I <sub>EBO</sub>	-	_	0.5	μA	$V_{EB} = 2V$
Static Forward Current Transfer Ratio (Note 10)	h <sub>FE</sub>	56	_	180	_	$I_C = 5mA$ , $V_{CE} = 10V$
Collector-Emitter Saturation Voltage (Note 10)	V <sub>CE(sat)</sub>	-	_	0.5	V	$I_C = 25$ mA, $I_B = 5$ mA
Transition Frequency (Note 10)	f⊤	1.4	3.2	_	GHz	$I_E = 25mA, V_{CE} = 5V,$ f = 500MHz
Collector Output Capacitance (Note 10)	$C_ob$	_	0.8	1.5	pF	V <sub>CB</sub> = 10V, f = 1MHz

lotes: 10. Measured under pulsed conditions. Pulse width ≤ 300µs. Duty cycle ≤ 2%

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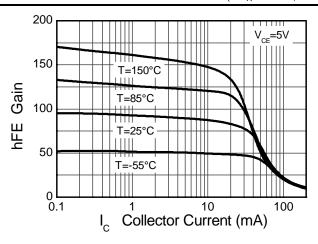


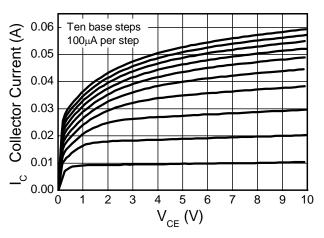
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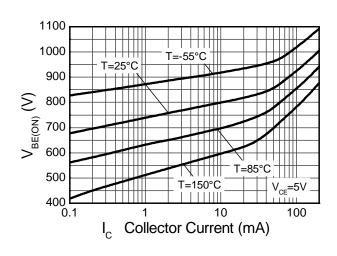


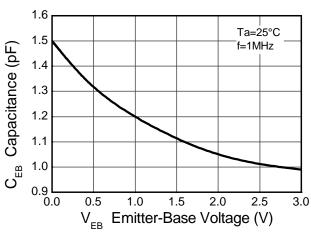
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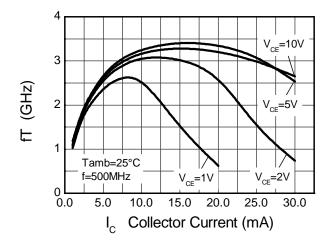
#### Typical Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

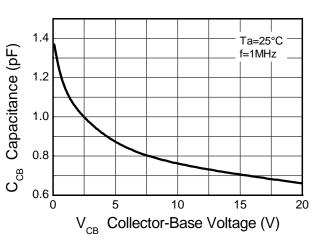












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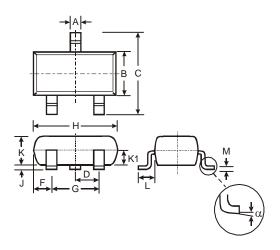




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### **Package Outline Dimensions**

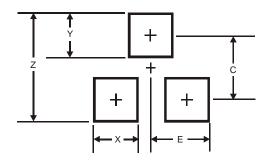
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



	SOT23					
Dim	Min	Max	Тур			
Α	0.37	0.51	0.40			
В	1.20	1.40	1.30			
С	2.30	2.50	2.40			
D	0.89	1.03	0.915			
F	0.45	0.60	0.535			
G	1.78	2.05	1.83			
Н	2.80	3.00	2.90			
J	0.013	0.10	0.05			
K	0.903	1.10	1.00			
K1	-		0.400			
L	0.45	0.61	0.55			
M	0.085	0.18	0.11			
α	0°	8°	-			
All	All Dimensions in mm					

## **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)		
Z	2.9		
Х	0.8		
Υ	0.9		
C	2.0		
E	1.35		



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